TOSHIBA PHOTOCOUPLER PHOTO RELAY

TLP227G(N),TLP227G-2(N)

CORDLESS TELEPHONE PBX MODEM

The TOSHIBA TLP227G series consist of a gallium arsenide infrared emitting diode optically coupled to a photo-MOS FET in a plastic DIP package.

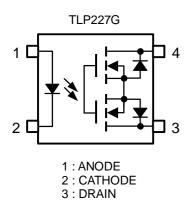
The TLP227G series are a bi-directional switch, which can replace mechanical relays in many applications.

FEATURES

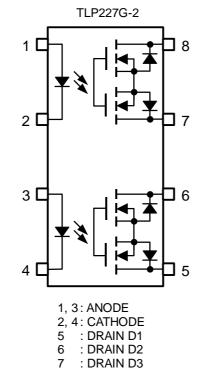
TLP227G-2

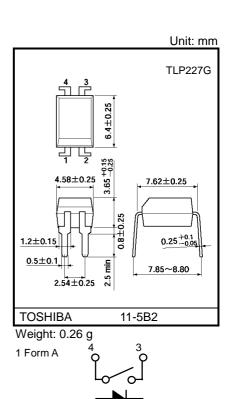
- TLP227G : 4 pin DIP (DIP4), 1 Channel Type (1 Form A)
 - : 8 pin DIP (DIP8), 2 Channel Type (2 Form A)
- Peak Off-State Voltage : 350 V (MIN.)
- Trigger LED Current 3 mA (MAX.)
- On-State Current : 120 mA (MAX.)
- On-State Resistance $\therefore 25 \Omega$ (MAX.)
- Isolation Voltage : 2500 Vrms (MIN.)

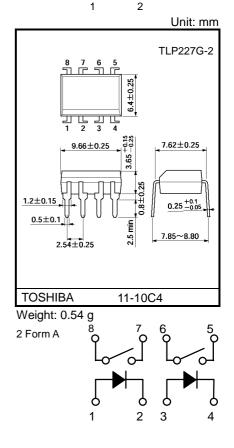
PIN CONFIGURATION (TOP VIEW)



4 : DRAIN





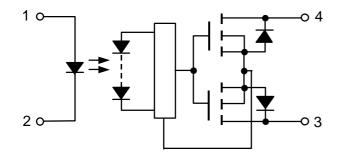


: DRAIN D4

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TOSHIBA

INTERNAL CIRCUIT



MAXIMUM RATINGS (Ta = 25°C)

	CHARACTE	SYMBOL	RATING	UNIT		
	Forward Current	١ _F	50	mA		
	Forward Current Derating (Ta \ge 25°C)	∆I _F /°C	-0.5	mA/°C		
LED	Peak Forward Current (100µs pulse, 10	0 pps)		I _{FP}	1	А
	Reverse Voltage			V _R	5	V
	Junction Temperature	Тj	125	°C		
	Off-State Output Terminal Voltage	VOFF	350	V		
	On-State Current	TLP227G				
۲		TLP227G-2	One Channel	I _{ON}	120	mA
СТО			Both Channel (Note 1)			
ETECTOR	On-State Current Derating (Ta≧25°C)	TLP227G				
		TI D0070 0	One Channel	∆l _{ON} /°C	-1.2	mA/°C
		TLP227G-2	Both Channel (Note 1)			
	Junction Temperature			Tj	125	°C
Stora	ige Temperature Range	T _{stg}	-55~125	°C		
Oper	Operating Temperature Range				-40~85	°C
Lead	Lead Soldering Temperature (10 s)				260	°C
Isolat	tion Voltage (AC, 1 minute, R.H. \leq 60%)	BVS	2500	Vrms		

(Note 1) :Two channels operating simultaneously.

(Note 2):Device considered a two-terminal device : LED side pins shorted together, and DETECTOR side pins shorted together.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V _{DD}	_	_	280	V
Forward Current	١ _F	5	7.5	25	mA
On-State Current	I _{ON}	_	_	120	mA
Operating Temperature	T _{opr}	-20		65	°C

INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
	Forward Voltage	V _F	I _F = 10 mA	1.0	1.15	1.3	V
LED	Reverse Current	I _R	$V_{R} = 5 V$	_	_	10	μA
	Capacitance	CT	V = 0, f = 1 MHz	_	30	_	pF
DETECTOR	Off-State Current	IOFF	V _{OFF} = 350 V			1	μΑ
	Capacitance	C _{OFF}	V = 0, f = 1 MHz		40		pF

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	I _{FT}	I _{ON} = 120 mA	_	1	3	mA
Close LED Current	I _{FC}	$I_{OFF} = 100 \ \mu A$	0.1	_	_	mA
On-State Resistance	R _{ON}	$I_{ON} = 120 \text{ mA}, I_F = 5 \text{ mA}$		14	25	Ω

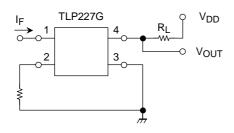
ISOLATION CHARACTERISTICS (Ta = 25°C)

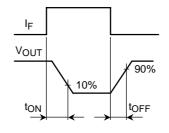
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance Input to Output	CS	$V_S = 0 V, f = 1 MHz$	—	0.8	_	pF
Isolation Resistance	R _S	$V_{S} = 500 \text{ V}, \text{ R.H.} \le 60\%$	$5 imes 10^{10}$	10 ¹⁴	_	Ω
		AC, 1 minute	2500	_	_	Vrms
Isolation Voltage	BVS	AC, 1 second (in oil)	—	5000	_	VIIIIS
		DC, 1 minute (in oil)	—	5000	_	Vdc

SWITCHING CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Turn-on Time		R _L = 200 Ω	_	0.3	1	ms
Turn-off Time	tOFF	$V_{DD} = 20 \text{ V}, \text{ I}_{\text{F}} = 5 \text{ mA}$ (Note 3)	_	0.1	1	1115

(Note 3): SWITCHING TIME TEST CIRCUIT





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